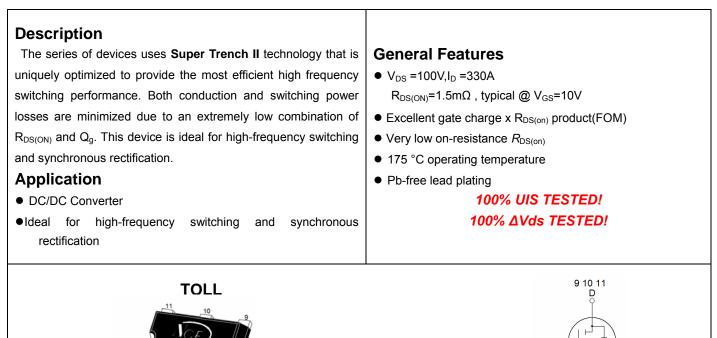


### NCE N-Channel Super Trench II Power MOSFET



#### Absolute Maximum Ratings (T<sub>c</sub>=25°Cunless otherwise noted)

Device Package

TOLL

Package Marking and Ordering Information

Device

NCEP020N10LL

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	VDS	100	V	
Gate-Source Voltage	Vgs	±20	V	
Drain Current-Continuous (T <sub>C</sub> =25°C)	I <sub>D</sub> (T <sub>C</sub> =25℃)	330	А	
Drain Current-Continuous(T <sub>C</sub> =100℃)	I <sub>D</sub> (T <sub>C</sub> =100℃)	240	А	
Drain Current-Continuous (T <sub>A</sub> =25°C)	I <sub>D</sub> (T <sub>A</sub> =25℃)	29.5	А	
Pulsed Drain Current (Note 1)	I <sub>DM</sub>	1320	А	
Maximum Power Dissipation (Tc=25 $^{\circ}$ C)	P <sub>D</sub> (T <sub>C</sub> =25℃)	400	W	
Maximum Power Dissipation (T <sub>A</sub> =25 °C)	P <sub>D</sub> (T <sub>A</sub> =25℃)	3.75	W	
Derating factor		2.67	W/℃	
Single pulse avalanche energy <sup>(Note 4)</sup>	E <sub>AS</sub>	2784	mJ	
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 175	°C	
Thermal Characteristic	·			
Thermal Resistance, Junction-to-Case	R <sub>eJC</sub>	0.38	°C/W	
Thermal Resistance, Junction-to-Ambient (Note 2)	R <sub>θJA</sub>	40	°C/W	

**Reel Size** 

**Device Marking** 

NCEP020N10LL

1Gc

Tape width

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2345678

Quantity

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Schematic Diagram



### Electrical Characteristics (T<sub>c</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Мах	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	$V_{GS}$ =0V I <sub>D</sub> =250 $\mu$ A	100		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20V, $V_{DS}$ =0V	-	-	±100	nA
On Characteristics (Note 2)	····					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2.0	3.0	4.0	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =165A	-	1.5	2.0	mΩ
Gate resistance	R <sub>G</sub>	F=1.0MHz	-	2.8	-	Ω
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =165A		200	-	S
Dynamic Characteristics (Note3)	····					
Input Capacitance	C <sub>lss</sub>		-	17000	-	PF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =50V,V <sub>GS</sub> =0V, F=1.0MHz	-	1500	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>		-	77	-	PF
Switching Characteristics (Note 3)						
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =50V,I <sub>D</sub> =165A V <sub>GS</sub> =10V,R <sub>G</sub> =1.6Ω	-	37	-	nS
Turn-on Rise Time	tr		-	29	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>		-	82	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	34	-	nS
Total Gate Charge	Qg		-	252	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =50V,I <sub>D</sub> =165A, V <sub>GS</sub> =10V	-	72		nC
Gate-Drain Charge	Q <sub>gd</sub>		-	63		nC
Drain-Source Diode Characteristics	····					
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =165A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	330	А
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25°C, I <sub>F</sub> = 165A	-	105	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note2)</sup>	-	290	-	nC

#### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. The value of R<sub>BJA</sub> is measured with the device mounted on 1in2 FR-4 board with 2oz. Copper, in a still air environment with T<sub>A</sub> =25° C. The value in any given application depends on the user's specific board design, and the maximum temperature of 175° C may be used if the PCB allows it.

3. Guaranteed by design, not subject to production

4. EAS condition : Tj=25  $^\circ C$  ,V\_DD=50V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$ 



# NCEP020N10LL

125

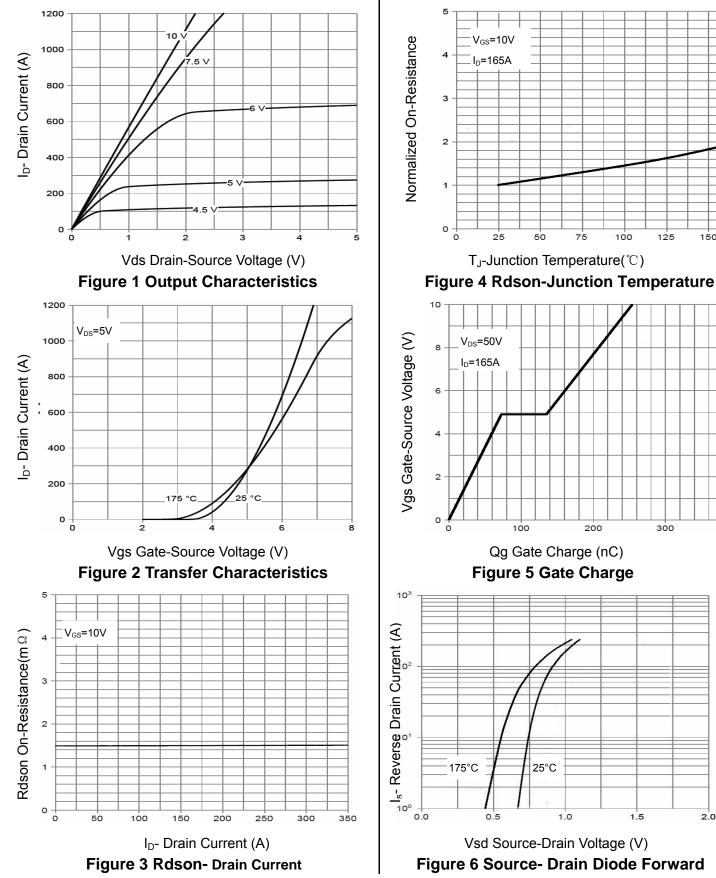
зо́о

150

175

400

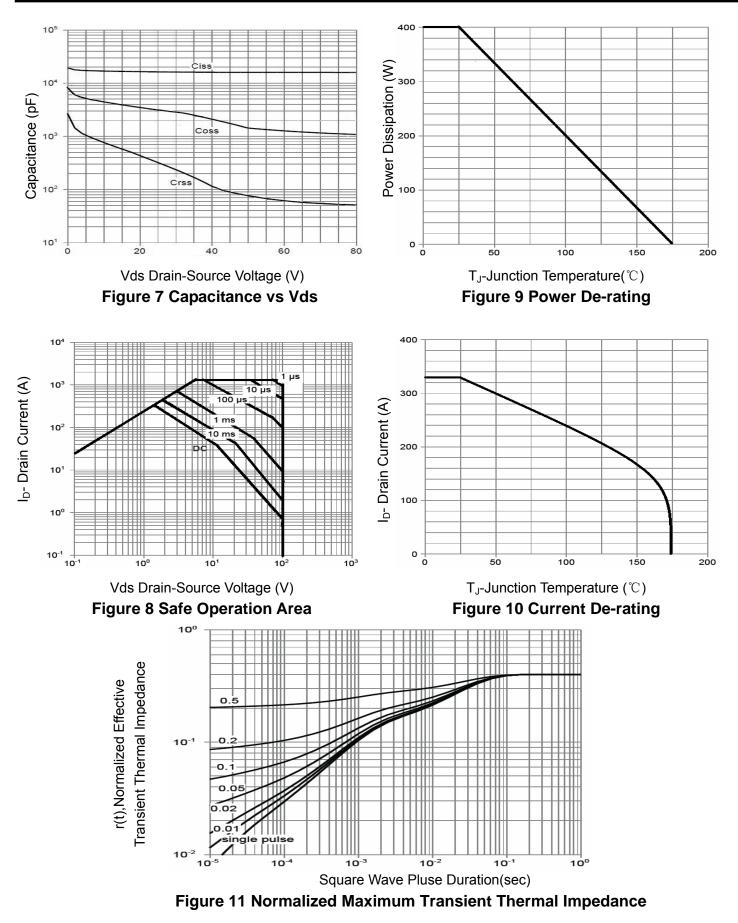
### **Typical Electrical and Thermal Characteristics**



2.0

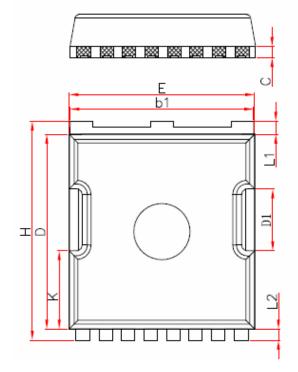


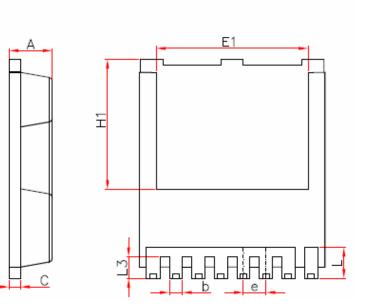
# NCEP020N10LL



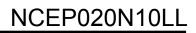


### **TOLL Package Information**





Symbol	Millimeters				
0911001	Min.	Nom.	Max.		
А	2.20	2.30	2.40		
b	0.65	0.75	0.85		
b1	9.70	9.80	9.90		
С	0.50	0.60	0.70		
D	10.30	10.40	10.50		
D1	3.15	3.3	3.45		
Е	9.70	9.90	10.10		
E1	8.00	8.10	8.20		
е	1.10	1.20	1.30		
Н	11.6	11.7	11.8		
H1	6.85	6.95	7.05		
K	4.08	4.18	4.28		
L	1.60	1.65	2.10		
L1	0.60	0.70	0.80		
L2	0.50	0.60	0.70		
L3	1.05	1.20	1.30		





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